

April 2013

# FDH15N50 / FDP15N50 / FDB15N50 N-Channel UniFET<sup>™</sup> MOSFET 500 V, 15 A, 380 mΩ

## Features

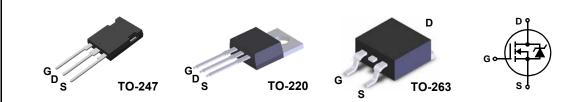
- Low gate charge  $Q_g$  results in simple drive requirement (Typ. 33 nC)
- Improved Gate, avalanche and high reapplied dv/dt
- ruggedness
- Reduced  $R_{DS(on)}$  ( 330m $\Omega$  ( Typ.) @ V<sub>GS</sub> = 10 V, I<sub>D</sub> = 7.5 A)
- Reduced Miller capacitance and low Input capacitance
- ( Typ. C<sub>rss</sub> = 16 pF)
- Improved switching speed with low EMI
- 175°C rated junction temperature

### Applications

- Lighting
- Uninterruptible Power Supply
- AC-DC Power Supply

### Description

UniFET<sup>TM</sup> MOSFET is Fairchild Semiconductor<sup>®</sup>'s high voltage MOSFET family based on planar stripe and DMOS technology. This MOSFET is tailored to reduce on-state resistance, and to provide better switching performance and higher avalanche energy strength. This device family is suitable for switching power converter applications such as power factor correction (PFC), flat panel display (FPD) TV power, ATX and electronic lamp ballasts.



### Absolute Maximum Ratings T<sub>C</sub> = 25°C unless otherwise noted

Symbol	Parameter	Ratings	Unit
V <sub>DSS</sub>	Drain to Source Voltage	500	V
V <sub>GS</sub>	Gate to Source Voltage	±30	V
۱ <sub>D</sub>	Drain Current		
	Continuous (T <sub>C</sub> = $25^{\circ}$ C, V <sub>GS</sub> = 10V)	15	A
	Continuous ( $T_C = 100^{\circ}C$ , $V_{GS} = 10V$ )	11	A
	Pulsed <sup>1</sup>	60	A
P <sub>D</sub>	Power dissipation	300	W
	Derate above 25°C	2	W/ºC
Γ <sub>J</sub> , T <sub>STG</sub>	Operating and Storage Temperature	-55 to 175	°C
	Soldering Temperature for 10 seconds	300 (1.6mm from case)	°C

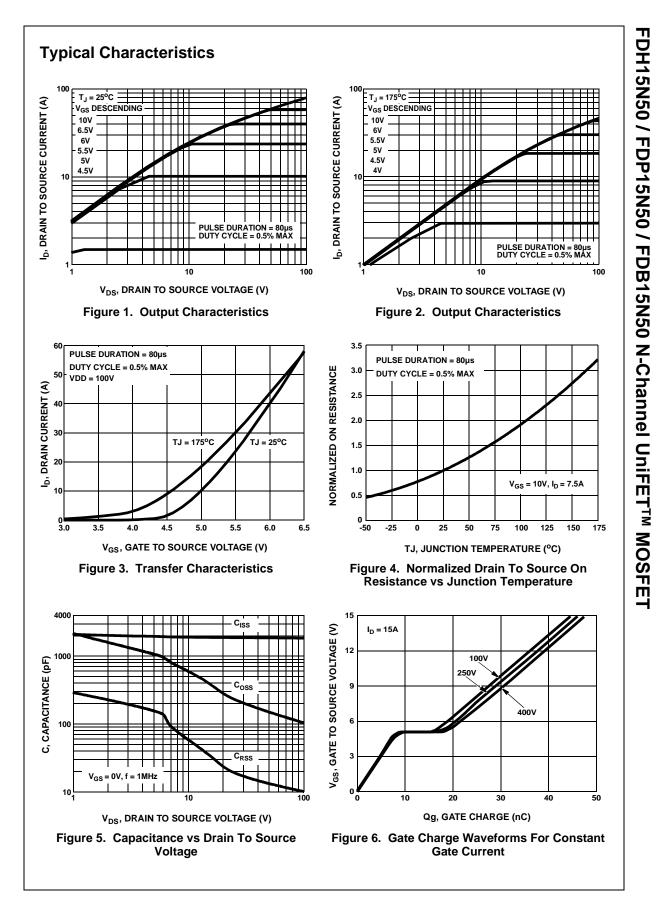
### **Thermal Characteristics**

$R_{ extsf{ heta}JC}$	Thermal Resistance Junction to Case	0.50	°C/W
$R_{\theta JA}$	Thermal Resistance Junction to Ambient (TO-247)	40	°C/W
$R_{\thetaJA}$	Thermal Resistance Junction to Ambient (TO-220, TO-263)	62	°C/W

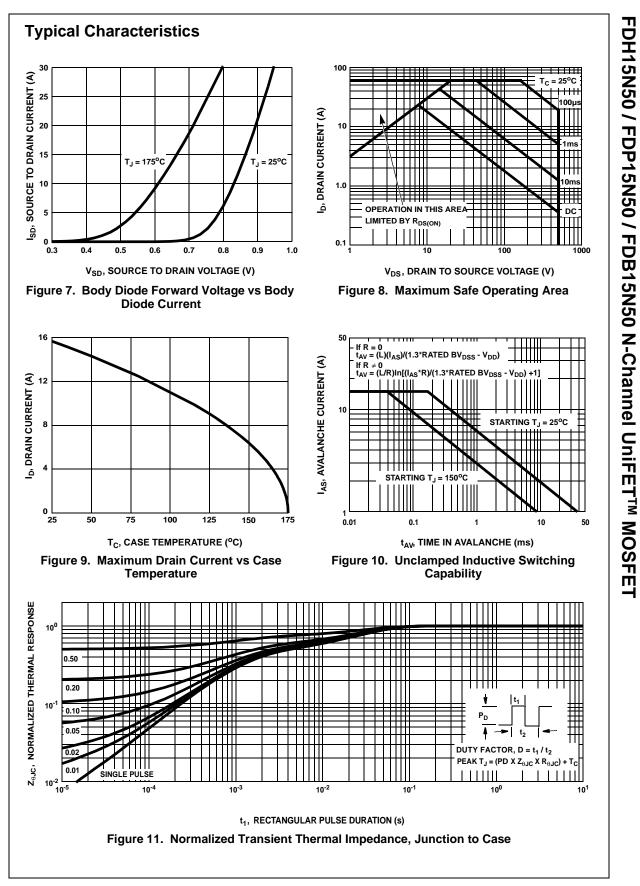
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Device M	/larking	Device	Package	Reel Size	Тар	e Width	Qua	antity
FDH15N50		FDH15N50	TO-247 Tube		-		30	
FDP15N50 FDP15N50		TO-220 Tube	Tube	- 24mm		50 800		
FDB15N50 FDB15N50		TO-263	330mm					
	al Char	acteristics T <sub>J</sub> = 25°C (	unless otherwis	se noted)				
Symbol		Parameter		conditions	Min	Тур	Мах	Unit
atics								
B <sub>VDSS</sub>	Drain to S	ource Breakdown Voltage	I <sub>D</sub> = 250μA,	$V_{GS} = 0V$	500	-	-	V
	J Breakdown Voltage Temp. Coefficient		Reference ID = 1mA	to 25ºC,	-	0.58	-	V/°C
r <sub>DS(ON)</sub>	Drain to S	Source On-Resistance	V <sub>GS</sub> = 10V,	l <sub>D</sub> = 7.5A	-	0.33	0.38	Ω
V <sub>GS(th)</sub>	Gate Thre	eshold Voltage	$V_{DS} = V_{GS},$	I <sub>D</sub> = 250μA	2.0	3.4	4.0	V
	Zoro Cota	Voltage Drain Current	V <sub>DS</sub> = 500V	$T_{\rm C} = 25^{\rm o}{\rm C}$	-	-	25	
IDSS			$V_{GS} = 0V$	$T_{C} = 150^{\circ}C$	-	-	250	μA
I <sub>GSS</sub>	Gate to S	ource Leakage Current	$V_{GS} = \pm 30V$		-	-	±100	nA
namics	5							-
g <sub>fs</sub>		Transconductance	V <sub>DD</sub> = 10V,	n = 7.5A	10	- 1	- 1	S
Q <sub>g(TOT)</sub>		e Charge at 10V	$V_{GS} = 10V,$		-	33	41	nC
Q <sub>qs</sub>	-	ource Gate Charge	$V_{GS} = 10V,$ $V_{DS} = 400V,$		-	7.2	10	nC
Q <sub>gd</sub>	-	rain "Miller" Charge	I <sub>D</sub> = 15A			12	16	nC
t <sub>d(ON)</sub>		Delay Time			-	9	-	ns
t <sub>r</sub>	Rise Time		00	$V_{DD} = 250V,$ $I_D = 15A,$ $R_G = 6.2\Omega,$		5.4	-	ns
t <sub>d(OFF)</sub>		Delay Time	$R_{G} = 6.2\Omega,$			26	-	ns
t <sub>f</sub>	Fall Time		$R_D = 17\Omega$		-	5	-	ns
C <sub>ISS</sub>	Input Cap	acitance			-	1850	-	pF
C <sub>OSS</sub>		apacitance	$V_{\text{DS}} = 25\text{V}, V_{\text{GS}} = 0\text{V},$		-	230	-	pF
C <sub>RSS</sub>	Reverse Transfer Capacitance		T = 1 MHZ	f = 1MHz		16	-	pF
valanch		teristics						
E <sub>AS</sub>	v	lse Avalanche Energy <sup>2</sup>			760	-	-	mJ
I <sub>AR</sub>	Avalanch	Avalanche Current			-	-	15	A
<sup>.</sup> ain-Soເ	urce Dioc	le Characteristics						
۱ <sub>S</sub>	Continuou (Body Dic	us Source Current ode)	MOSFET sy showing the		-	-	15	А
I <sub>SM</sub>	Pulsed So (Body Dic	ource Current <sup>1</sup> ode)	integral reverse p-n junction diode.		-	-	60	А
$V_{SD}$	Source to	Drain Diode Voltage	I <sub>SD</sub> = 15A		-	0.86	1.2	V
t <sub>rr</sub>	Reverse F	Recovery Time	I <sub>SD</sub> = 15A, di <sub>SD</sub> /dt = 100A/µs		-	470	730	ns
Q <sub>RR</sub>	Reverse F	Recovered Charge	I <sub>SD</sub> = 15A, di <sub>SD</sub> /dt = 100A/µs		-	5	6.6	μC
	ing; pulse width 25°C, L = 7.0m	limited by maximum junction temperal H, I <sub>AS</sub> = 15A	ture					

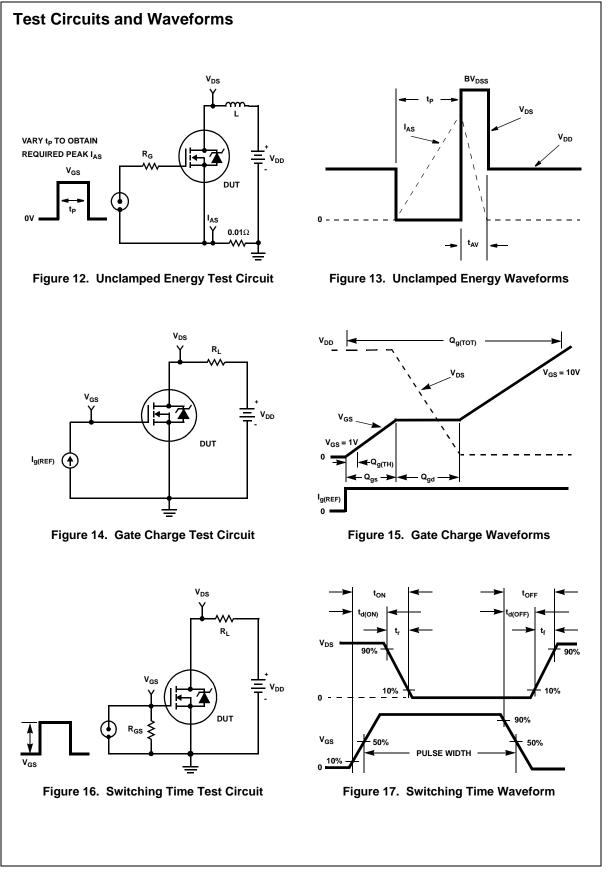
FDH15N50 / FDP15N50 / FDB15N50 N-Channel UniFET<sup>™</sup> MOSFET



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